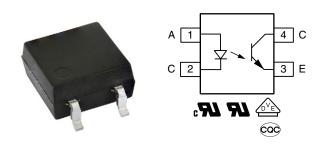


Optocoupler, Phototransistor Output, Low Input Current, SOP-4, Mini-Flat Package



LINKS TO ADDITIONAL RESOURCES







DESCRIPTION

The VOMA617A series has a GaAlAs infrared emitting diode, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4-pin mini-flat package.

It features a high current transfer ratio at low input current, low coupling capacitance, and high isolation voltage.

The coupling devices are designed for signal transmission between two electrically separated circuits, specifically for use in automotive, as well as high reliable industrial applications.

FEATURES

- AEC-Q102 qualified
- High CTR with low input current
- SOP-4 low profile package
- High collector emitter voltage, V_{CFO} = 80 V
- Isolation test voltage = 3750 V_{RMS}
- · Low coupling capacitance
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912







APPLICATIONS

- · Galvanic and noise isolation
- Signal transmission
- Hybrid / electric vehicle applications
- · Battery management
- 48 V board net
- System control

AGENCY APPROVALS

- UL1577
- cUL 1577
- <u>DIN EN 60747-5-5 (VDE 0884-5)</u>
- CQC GB4943.1-2011

ORDERING INFORMATION				
V O M A 6 1 7 A - # X 0 0 1 T				
PART NUMBER	PART NUMBER CTR PACKAGE OPTION TAPE BIN AND REEL ≥ 5 mm REEL			<u>→ ≥ 5 mm</u>
AGENCY CERTIFIED / PACKAGE		CTR	1 (%)	
AGENCY CERTIFIED / PACKAGE	5 mA			
UL, cUL, VDE, CQC	50 to 600	100 to 200	160 to 320	130 to 260
SOP-4	VOMA617A-X001T	VOMA617A-3X001T	VOMA617A-4X001T	VOMA617A-8X001T

Note

· Additional options may be possible, please contact sales office



www.vishay.com

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	5	V
Power dissipation		P _{diss}	30	mW
Forward current		l _F	20	mA
Surge forward current	t _p ≤ 10 μs	I _{FSM}	0.5	Α
Junction temperature		Tj	125	°C
OUTPUT				
Collector emitter voltage		V_{CEO}	80	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		Ic	50	mA
Power dissipation		P _{diss}	150	mW
Junction temperature		T _j	125	°C
COUPLER				
Total power dissipation		P _{tot}	180	mW
Storage temperature range		T _{stg}	-40 to +150	°C
Ambient temperature range		T _{amb}	-40 to +110	°C
Soldering temperature	t = 10 s	T _{sld}	260	°C

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability

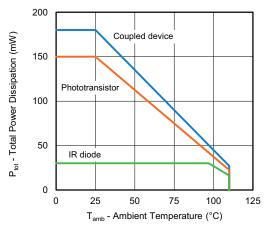


Fig. 1 - Power Dissipation vs. Ambient Temperature

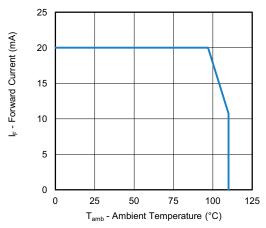


Fig. 2 - Maximum Forward Current vs. Ambient Temperature



ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT	•					
Forward voltage	$I_F = 5 \text{ mA}$	V_{F}	-	1.33	1.5	V
Reverse current	V _R = 5 V	I _R	-	-	10	μΑ
Capacitance	$V_R = 0 V, f = 1 MHz$	CI	-	40	-	pF
Thermal resistance		R_{thJA}	-	1000	-	K/W
OUTPUT						
Collector emitter leakage current	V _{CE} = 50 V	I _{CEO}	-	1	100	nA
Collector emitter breakdown voltage	I _C = 100 μA	BV_{CEO}	80	-	-	V
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz	C _{CE}	-	7	-	pF
Thermal resistance		R_{thJA}	-	667	-	K/W
COUPLER						
Collector emitter saturation voltage	$I_F = 5 \text{ mA}, I_C = 1.25 \text{ mA}$	V _{CEsat}	-	0.25	0.4	V
Cut-off frequency	$I_F = 10$ mA, $V_{CC} = 5$ V, $R_L = 100$ Ω	f _{CTR}	=	165	-	kHz
Coupling capacitance	f = 1 MHz	C _{IO}	-	1.2	-	pF
Thermal resistance		R_{thJA}	-	556	-	K/W

Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_{C}/I_{F} $I_{F} = 5 \text{ mA, } V_{C}$		VOMA617A	CTR	50	-	600	%
		VOMA617A-3	CTR	100	-	200	%
	$I_F = 3 \text{ IIIA}, V_{CE} = 3 \text{ V}$	VOMA617A-4	CTR	160	-	320	%
		VOMA617A-8	CTR	130	-	260	%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED						
Rise time		t _r	=	1.8	-	μs
Fall time	$I_{C} = 2 \text{ mA}, V_{CC} = 5 \text{ V},$	t _f	=	2.2	-	μs
Turn-on time	$R_L = 100 \Omega$	t _{on}	=	2.5	-	μs
Turn-off time		t _{off}	=	3.0	-	μs
SATURATED						
Rise time		t _r	-	1.2	-	μs
Fall time	$I_F = 5 \text{ mA}, V_{CC} = 5 \text{ V},$	t _f	-	5.7	-	μs
Turn-on time	$R_L = 1.9 \text{ k}\Omega$	t _{on}	=	1.7	-	μs
Turn-off time		t _{off}	-	11.2	-	μs



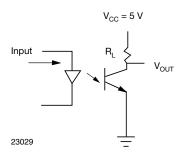


Fig. 3 - Test Circuit for Switching Characteristics

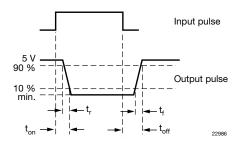


Fig. 4 - Parameter and Limit Definition

PARAMETER PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1	OTHIBOL	40 / 110 / 21	Oitii
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V _{ISO}	3750	V_{RMS}
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V _{IOTM}	6000	V_{peak}
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V _{IORM}	707	V _{peak}
	T _{amb} = 25 °C, V _{IO} = 500 V	R _{IO}	≥ 10 ¹²	Ω
Isolation resistance	$T_{amb} = 100 ^{\circ}\text{C}, V_{IO} = 500 \text{V}$	R _{IO}	≥ 10 ¹¹	Ω
	$T_{amb} = T_S$, $V_{IO} = 500 \text{ V}$	R _{IO}	≥ 10 ⁹	Ω
Output safety power		P _{SO}	550	mW
Input safety current		I _{SI}	180	mA
Input safety temperature		T _S	175	°C
Creepage distance			≥ 5	mm
Clearance distance			≥ 5	mm

Note

As per IEC 60747-5-5, § 5.5.4.9.3, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

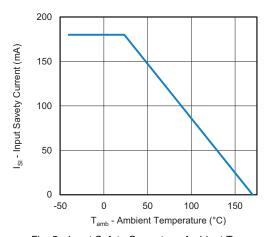


Fig. 5 - Input Safety Current vs. Ambient Temperature

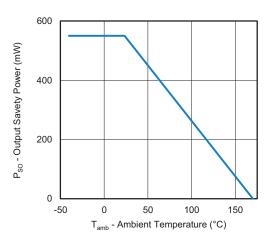


Fig. 6 - Output Safety Power vs. Ambient Temperature

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

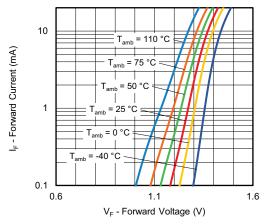
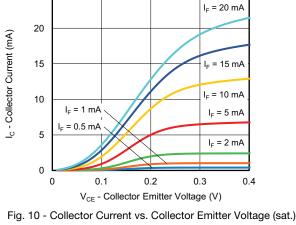


Fig. 7 - Forward Current vs. Forward Voltage



25

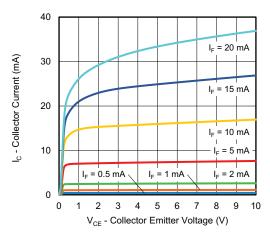


Fig. 8 - Collector Current vs. Collector Emitter Voltage (non-sat.)

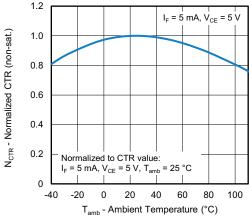


Fig. 11 - Normalized CTR (non-sat.) vs. Ambient Temperature

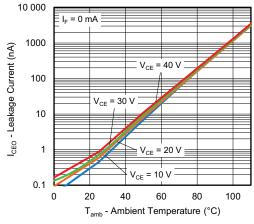


Fig. 9 - Leakage Current vs. Ambient Temperature

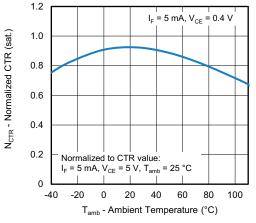


Fig. 12 - Normalized CTR (sat.) vs. Ambient Temperature

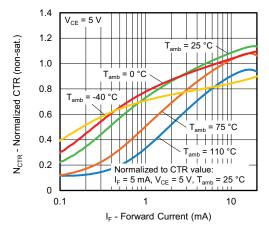


Fig. 13 - Normalized CTR (non-sat.) vs. Forward Current

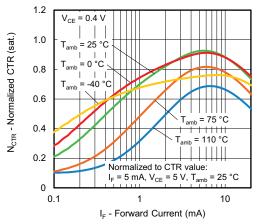


Fig. 14 - Normalized CTR (sat.) vs. Forward Current

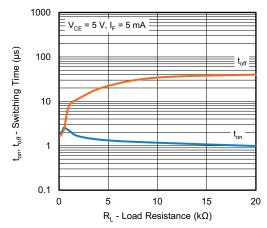


Fig. 15 - Switching Time vs. Load Resistance

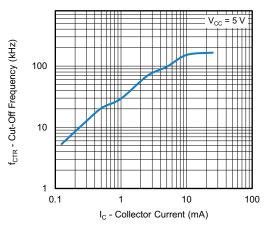


Fig. 16 - Cut-Off Frequency vs. Collector Current

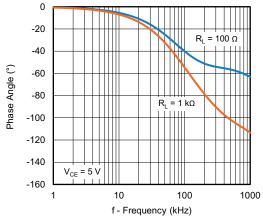


Fig. 17 - Phase Angle vs. Frequency



PACKAGE DIMENSIONS (in millimeters)

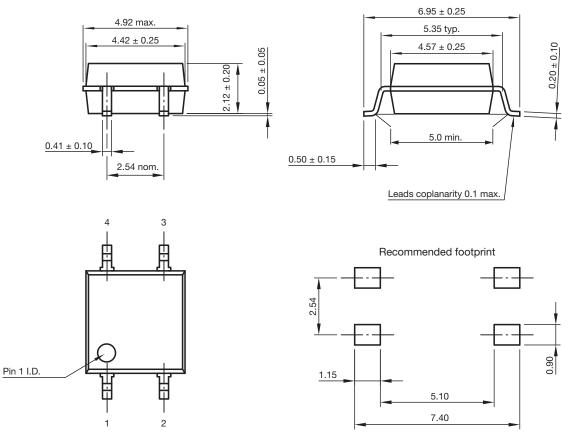
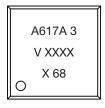


Fig. 18 - Package Drawing

PACKAGE MARKING (example of VOMA617A-3X001T)



Notes

- XXXX = LMC (lot marking code)
- Option 1 is reflected with letter "X"
- Tape and reel suffix (T) is not part of the package marking

PACKAGING INFORMATION (in millimeters)

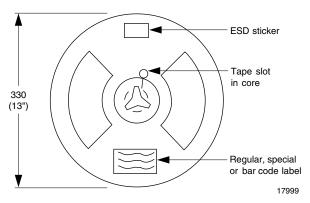
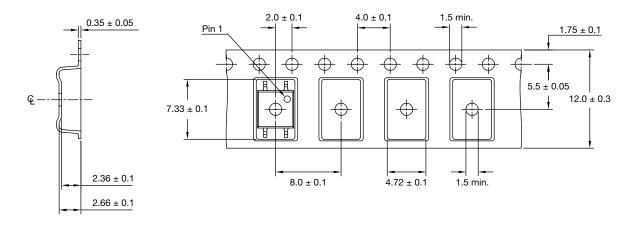


Fig. 19 - Tape and Reel Shipping Medium (EIA-481, revision A, and IEC 60286)



Note

• Cummulative tolerance of 10 spocket holes is 0.20 mm

Fig. 20 - Tape and Reel Packing

TAPE AND REEL PACKING				
TYPE	UNITS/REEL			
SOP-4	2000			

SOLDER PROFILES

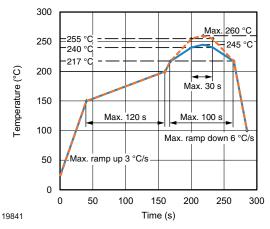


Fig. 21 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 3, according to J-STD-020.

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-033D.

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